Substitute for form 1449A/PTO				Complete if Known		
INFO	DMATION I	DISC	AGUER	Application Number	New Application	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Filing Date	October 16, 2003			
SIA			First Named Inventor	Shinji MAEKAWA		
	(use as many sheets as necessary)			Art Unit		
				Examiner Name		
Sheet	<u> </u>	of	1	Attorney Docket Number	740756-2660	

			U.S. PATENT DOCUME	ENTS		
Examiner Initials	Cite No.	U.S. Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where Relevant Passages or Relevant	
		Number - Kind Code <sup>2</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Figures Appear	
NG		US-5,643,826	07/01/1997	Ohtani et al.		
		US-5,923,962	07/13/1999	Ohtani et al.		
		US-5,543,352	08/06/1996	Ohtani et al.		
		US-5,612,250	03/18/1997	Ohtani et al.		
		US-2001/0052950 A1	12/20/2001	Yamazaki et al.		
	}	US-6,426,245 B1	07/30/2002	Kawasaki et al.		
		US-2002/0146874 A1	10/10/2002	Kawasaki et al.		
	]	US-5,953,597	09/14/1999	Kusumoto et al.		
		US-5,612,251	03/18/1997	Lee		
	1	US-5,767,003	07/16/1998	Noguchi		
	1	US-5,953,597	09/14/1999	Kusumoto et al.		
		US-6,020,224	02/01/2000	Shimogaichi et al.		
		US-6,246,524 B1	06/12/2001	Tanaka		
		US-6,248,606 B1	06/19/2001	Ino et al.		
10	Ī	US-6,380,009 B1	04/30/2002	Battersby		

		F	OREIGN PATENT	DOCUMENTS			
Examiner Initials*	Cite No.1	Foreign Patent Document	Publication Date	Name of Patentee or Application of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	τ•	
		Country Code <sup>3</sup> Number <sup>4</sup> (if known)	MM-DD-YYYY				
06		JP 07-130652	05/19/1995	Otani et al.		Abstract	
	Ţ -	EP 0 651 431 A2	05/03/1995	Ohtani et al.		Full	
		JP 07-161634	06/23/1995	Otani et al.		Abstract	
		JP 2001-345453	12/14/2001	Yamazaki et al.		Abstract	
	.	JP2001-85703	03/30/2001	Kawasaki et al.		Abstract	
05		JP 08/228006	09/03/1996	Kusumoto et al.		Abstract	
		OTHER PRIOR	ART – NON PATENT	LITERATURE DOCUMENTS		_	
Examiner Initials Cite Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published.							
Kazuhiro SHIMIZU et al., "High-Mobility Poly-Si Thin-Film Transistors Fabricated by a Novel Excimer Laser Crystallization Method", IEEE TRANSACTIONS ON ELECTRON DEVICES., VOL. 40, NO. 1, pp. 112-117.							

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Considered

Signature

<sup>&</sup>lt;sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kinds Codes of USPTO Patent Documents at <a href="www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

<sup>&</sup>lt;sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> Applicant is to place a check mark here if English language Translation is attached.